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Hollowed Net for On-device Personalization of Text-to-Image Diffusion Models

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On-Device Personalization of T2I Diffusion Models

Task Definition

- We aim to enable **on-device personalization** of T2I diffusion models, by **fine-tuning** models on the mobile devices **with user-specific images** for customized generation.
- On-device personalization can make the entire user experience **all-the-more personal** and help **protect users' privacy** since personal information remain solely on the device.





On-Device Personalization of T2I Diffusion Models

Challenges

- The challenge of on-device learning stems from **limited computational resources** of end device, particularly in terms of **memory I/O**.
- Existing PEFT methods are **limited in extremely low memory resources** as they require backpropagation over large diffusion models and **do not reduce memory usage from loading model weights.**



LoRA personalization with Hollowed Net

Motivation

- We find that the blocks around the center of the diffusion U-Net are less involved in the personalization.
- Building on this insight, we design Hollowed Net, which can **temporarily excluding these less significant layers during fine-tuning** to reduce peak memory usage.



LoRA personalization with Hollowed Net

Training w/ Hollowed Net

- We propose two-stage fine-tuning strategy:
 - **1. Pre-computing** intermediate activations of the original diffusion U-Net
 - 2. Fine-tuning the Hollowed Net using the pre-computed activations



LoRA personalization with Hollowed Net

Inference w/ Personalized LoRA

- Hollowed Net **does not need to be held during inference**, by transferring personalized LoRA parameters to the original U-Net.
- We sequentially execute two inference paths, respectively corresponding to each stage of fine-tuning.



Experimental Results

Comparison with Full / LoRA FT

- We conduct experiments with 131 subjects and demonstrate that Hollowed Net achieves high-fidelity personalization results comparable to Full FT while requiring 77% (12.74GB) less GPU memory.
- The required memory for Hollowed Net fine-tuning is only 11% (390MB) more than needed for inference.

Method	# of Parameters		Traini	Training Memory		DreamBooth			CustomConcept101		
	Base	LoRA	Peak	Comp. w/ Inf.	DINO	CLIP-I	CLIP-T	DINO	CLIP-I	CLIP-T	
Full FT	866M	-	16.62GB	+376%	0.663 ± 0.013	$0.802 \\ \pm 0.007$	$0.302 \\ \pm 0.002$	$0.605 \\ \pm 0.005$	0.773 ± 0.006	$0.302 \\ \pm 0.002$	
LoRA FT (r=128)	866M	27M	5.23GB	+50%	0.658 ± 0.001	$\substack{0.806\\\pm0.005}$	$0.299 \\ \pm 0.002$	$0.603 \\ \pm 0.008$	0.773 ± 0.005	$0.302 \\ \pm 0.002$	
LoRA FT (r=1)	866M	207K	4.84GB	+39%	$\substack{0.516\\\pm0.011}$	$0.738 \\ \pm 0.003$	$\substack{0.314\\\pm0.001}$	$0.522 \\ \pm 0.008$	$0.737 \\ \pm 0.005$	$0.305 \\ \pm 0.001$	
Hollowed Net (Ours)	527M	24M	3.88GB	+11%	$0.660 \\ \pm 0.011$	$0.805 \\ \pm 0.006$	$\underset{\pm 0.001}{0.300}$	$0.603 \\ \pm 0.007$	$0.773 \\ \pm 0.005$	$\substack{0.302\\\pm0.002}$	

Experimental Results

Qualitative Results

• Hollowed Net effectively captures the visual details of the target subjects, while maintaining high text-image alignment for different types of applications including property modification, recontextualization, accessorization, and artistic rendition.





Experimental Results

Fractions of Hollowed Layers

- We find that the model's capacity to preserve subject fidelity remains comparable to or slightly better than LoRA FT **until around 39.2% of layers are hollowed.**
- Users can adjust the fraction of hollowed layers to control the trade-offs between performance and memory requirements, depending on the target application and resources.



Thank you

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